SONY

CXD2043Q

Digital Comb Filter (NTSC)

Description

The CXD2043Q is an adaptive comb filter compatible with NTSC system, and can provide high-precision Y/C separation with a single-chip.

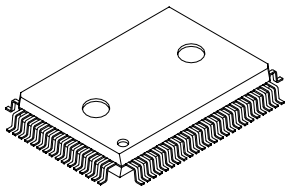
Features

- Y/C separation by adaptive processing
- Horizontal aperture compensation circuit
- 8-bit A/D converter (1-channel)
- 8-bit D/A converter (2-channel)
- Two 1H delay lines
- 4-PLL

Absolute Maximum Ratings (Ta = 25°C, Vss = 0V)

• Supply voltage	DV_{DD}	V_{SS} – 0.5 to +7.0	V
	YV_{DD}	V_{SS} – 0.5 to +7.0	V
	CV_{DD}	V_{SS} – 0.5 to +7.0	V
	PV_{DD}	V_{SS} – 0.5 to +7.0	V
• Input voltage	V_I	V_{SS} – 0.5 to V_{DD} + 0.5	V
• Output voltage	V_O	V_{SS} – 0.5 to V_{DD} + 0.5	V
• Operating temperature			
	Topr	–20 to +75	°C
• Storage temperature			
	Tstg	–55 to +150	°C

80 pin QFP (Plastic)



Recommended Operating Conditions

• Supply voltage	DV_{DD}	5.0 ± 0.25	V
	YV_{DD}	5.0 ± 0.25	V
	CV_{DD}	5.0 ± 0.25	V
	PV_{DD}	5.0 ± 0.25	V
• Operating temperature			
	Topr	–20 to +75	°C

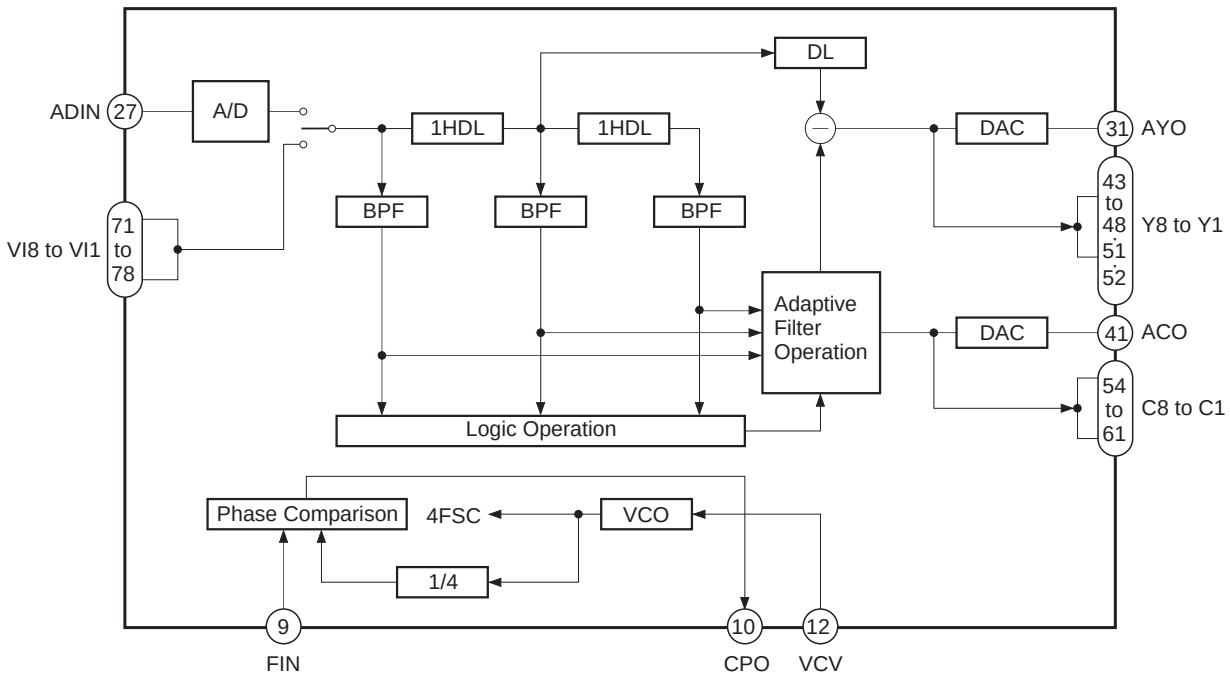
Structure

Silicon gate CMOS IC

Applications

Y/C separation for color TVs and VCRs

Block Diagram



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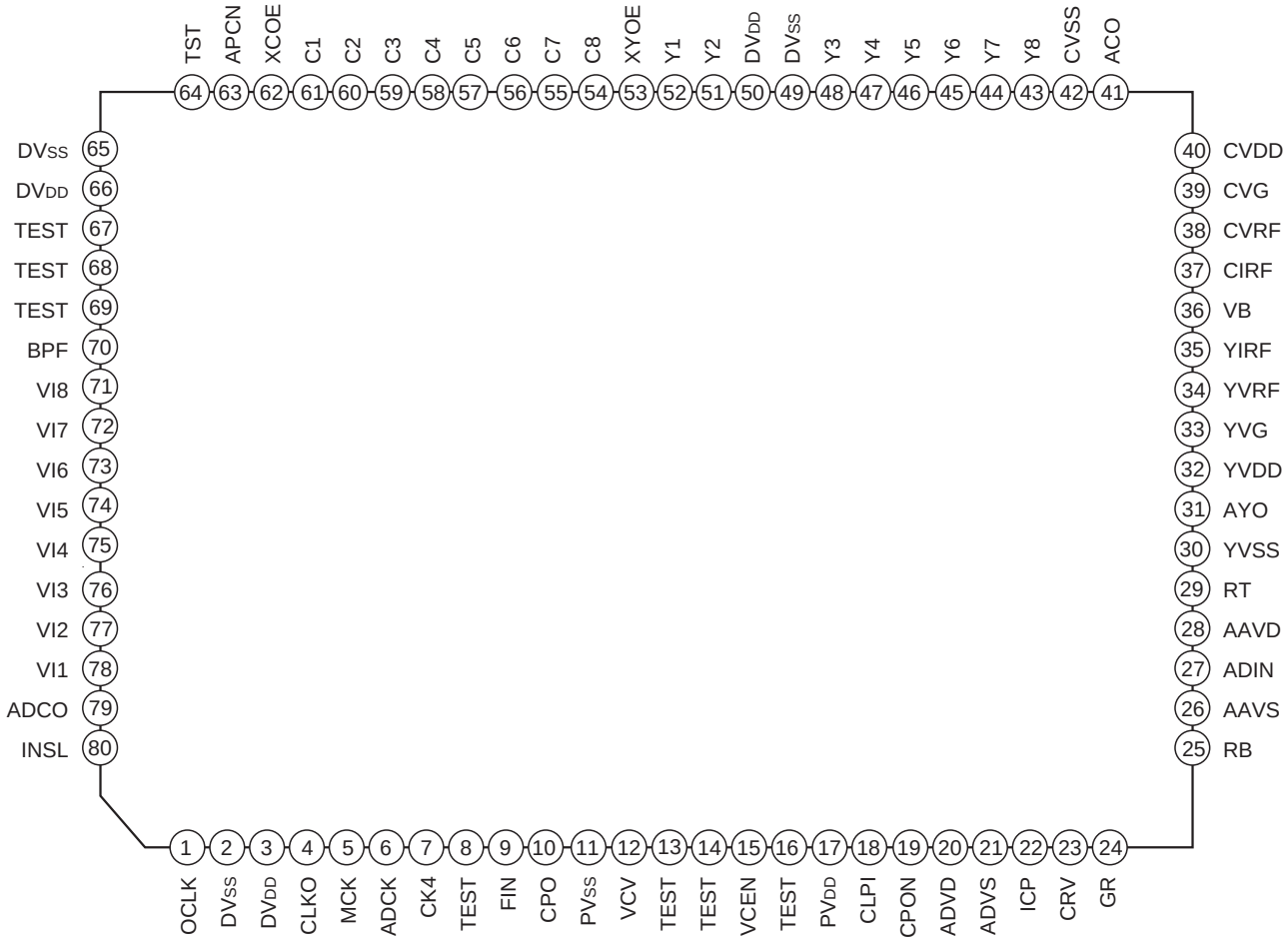
Pin Configuration



Pin Description

Pin No.	Symbol	I/O	Description
1	OCLK	I	Clock amplifier input. Input at 0.8Vp-p or more by eliminating DC components with a capacitor.
2	DVSS	—	Digital ground
3	DVDD	—	Digital power supply
4	CLKO	O	Clock amplifier output. Left open when the clock amplifier is not used.
5	MCK	I	Master clock input
6	ADCK	I	Clock input for A/D converter. Input the same clock signal as for Pin 5.
7	CK4	O	4FSC clock output. Generated from the built-in 4-PLL.
8	TEST	I	Test. Fix to Low.
9	FIN	I	FSC clock input. Input FSC which is burst-locked. Connect to DVss when the PLL is not used.
10	CPO	O	Phase comparison output for the built-in PLL. Left open when the PLL is not used.
11	PVSS	—	PLL analog ground

Pin No.	Symbol	I/O	Description
12	VCV	I	Control voltage input for the built-in VCO oscillation. Connect to PVss when the PLL is not used.
13	TEST	I	Test. Fix to Low.
14	TEST	I	Test. Fix to Low.
15	VCEN	I	Built-in VCO oscillation enable. Connect to PV_{DD} when using the PLL. Connect to PVss when the PLL is not used.
16	TEST	O	Test. Left open.
17	PV_{DD}	—	PLL analog power supply
18	CLPI	I	Clamp pulse input for A/D converter (negative polarity). Connect to DV_{DD} when the clamp is off.
19	CPON	I	High: Clamp function is set to off, and only the normal A/D converter function is enabled. Low: Clamp function is enabled.
20	ADVD	—	Digital power supply for A/D converter
21	ADVS	—	Digital ground for A/D converter
22	ICP	I	Clamp control voltage
23	CRV	I	Clamp reference voltage input
24	GR	—	Connect to analog ground.
25	RB	O	A/D converter reference voltage (bottom)
26	AAVS	—	Analog ground for A/D converter
27	ADIN	I	Comb filter analog input (A/D converter input)
28	AAVD	—	Analog power supply for A/D converter
29	RT	O	A/D converter reference voltage (top)
30	YVSS	—	Analog ground for Y-D/A converter
31	AYO	O	Analog luminance signal output
32	YVDD	—	Analog power supply for Y-D/A converter
33	YVG	O	Connect to YVDD via a capacitor of approximately 0.1µF.
34	YVRF	I	VRF for Y. Sets the output full-scale value for Y.
35	YIRF	I	Connect a resistor of 16 times (16R) that of the output resistor "R" of AYO pin.
36	VB	O	Connect to YVss via a capacitor of approximately 0.1µF.
37	CIRF	O	Connect a resistor of 16 times (16R) that of the output resistor "R" of ACO pin.
38	CVRF	I	VRF for C. Sets the output full-scale value for C.
39	CVG	O	Connect to CVDD via a capacitor of approximately 0.1µF.
40	CVDD	—	Analog power supply for C-D/A converter
41	ACO	O	Analog chroma signal output
42	CVSS	—	Analog ground for C-D/A converter
43	Y8	O	Digital luminance signal output (MSB)
44	Y7	O	Digital luminance signal output
45	Y6	O	Digital luminance signal output

Pin No.	Symbol	I/O	Description
46	Y5	O	Digital luminance signal output
47	Y4	O	Digital luminance signal output
48	Y3	O	Digital luminance signal output
49	DV_{SS}	—	Digital ground
50	DV_{DD}	—	Digital power supply
51	Y2	O	Digital luminance signal output
52	Y1	O	Digital luminance signal output (LSB)
53	XYOE	I	Digital luminance signal output control High: High impedance Low: Standard output
54	C8	O	Digital chroma signal output (MSB)
55	C7	O	Digital chroma signal output
56	C6	O	Digital chroma signal output
57	C5	O	Digital chroma signal output
58	C4	O	Digital chroma signal output
59	C3	O	Digital chroma signal output
60	C2	O	Digital chroma signal output
61	C1	O	Digital chroma signal output (LSB)
62	XCOE	I	Digital chroma signal output control. High: High impedance Low: Standard output
63	APCN	I	Aperture compensation switching. High: Aperture compensation ON Low: Aperture compensation OFF
64	TST	I	Y output through mode. High: Outputs the input composite video signal from the Y output. At this time, there is 1H + 18 clock delay from the input. Low: Y/C separation mode
65	DV_{SS}	—	Digital ground
66	DV_{DD}	—	Digital power supply
67	TEST	I	Test. Fix to Low.
68	TEST	I	Test. Fix to Low.
69	TEST	I	Test. Fix to Low.
70	BPF	I	High: Fixed to BPF separation Low: Standard mode
71	VI8	I	Digital composite video input (MSB)
72	VI7	I	Digital composite video input
73	VI6	I	Digital composite video input
74	VI5	I	Digital composite video input
75	VI4	I	Digital composite video input
76	VI3	I	Digital composite video input

Pin No.	Symbol	I/O	Description
77	VI2	I	Digital composite video input
78	VI1	I	Digital composite video input (LSB)
79	ADCO	I	High: Video signals taken in form A/D converter are output from the Y output pins (Y8 to Y1) as 8-bit digital data with a 3.5 clock delay. Low: Normal mode
80	INSL	I	Input switching. High: Digital input Low: Analog input.

Electrical Characteristics

DC Characteristics

(V_{DD} = 5 ± 0.25V, V_{SS} = 0V, Ta = –20 to +75°C)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Supply voltage	DV_{DD}	—	4.75	5.0	5.25	V
	AAVD					
	ADVD					
	YVDD					
	CVDD					
Operating temperature	Topr	—	–20	—	+75	°C
Supply current	I_{DD}	Clock 14MHz	—	—	80	mA
High level input voltage	V_{IH}	CMOS level	$V_{DD} \times 0.7$	—	V_{DD}	V
Low level input voltage	V_{IL}	CMOS level	V_{SS}	—	$V_{DD} \times 0.3$	V
High level output voltage	V_{OH}	I_{OH} = –2mA	V_{DD} – 0.8	—	V_{DD}	V
		I_{OH} = –4mA (Pins 4, 7)				
Low level output voltage	V_{OL}	I_{OL} = 4mA	V_{SS}	—	0.4	
		I_{OL} = 8mA (Pins 4, 7)				
Logical Vth	LVth	OCLK (Pin 1)	—	V_{DD}/2	—	V
Input voltage	V_{IN}		0.8	—	V_{DD}	Vp-p
Feedback resistor	R_{FB}		250k	1M	2.5M	Ω

AC Characteristics

(V_{DD} = 5 ± 0.25V, V_{SS} = 0V, Ta = –20 to +75°C, C_L = 20pF)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Data setup time	tdsu	MCK → VI [8 : 1]	15.0	—	—	ns
Data hold time	tdh	MCK → VI [8 : 1]	10.0	—	—	ns
Propagation delay time	tpd	MCK → Y [A : 1] MCK → C [A : 1]	—	—	40	ns
Clock frequency	f	—	14	4fsc	15	MHz

Pin Capacitance

(Ta = 25°C, f = 1MHz, V_{IN} = V_{OUT} = 0V)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Input capacitance	C_{IN}	—	—	—	9	pF
Output capacitance	C_{OUT}	—	—	—	11	pF

ADC Characteristics (V_{DD} = 5V, Ta = 25°C, f = 10MHz)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Resolution	n		—	8	—	bit
Max. conversion speed	fmax		14.3	—	—	MSPS
Analog input band width	BW	–3dB	—	18	—	MHz
Self bias	VRB		0.48	0.52	0.56	V
	VRT – VRB		1.96	2.08	2.22	V
Propagation delay time	tpd		—	—	45	ns
Differential linearity error	E_D		–1.0	—	+1.0	LSB
Integral linearity error	E_L		–3.0	—	+3.0	LSB
Clamp offset voltage	E_{OC}	V_{REF} = VRB	–20	0	+20	mV
		V_{REF} = VRT	–30	–10	+10	mV

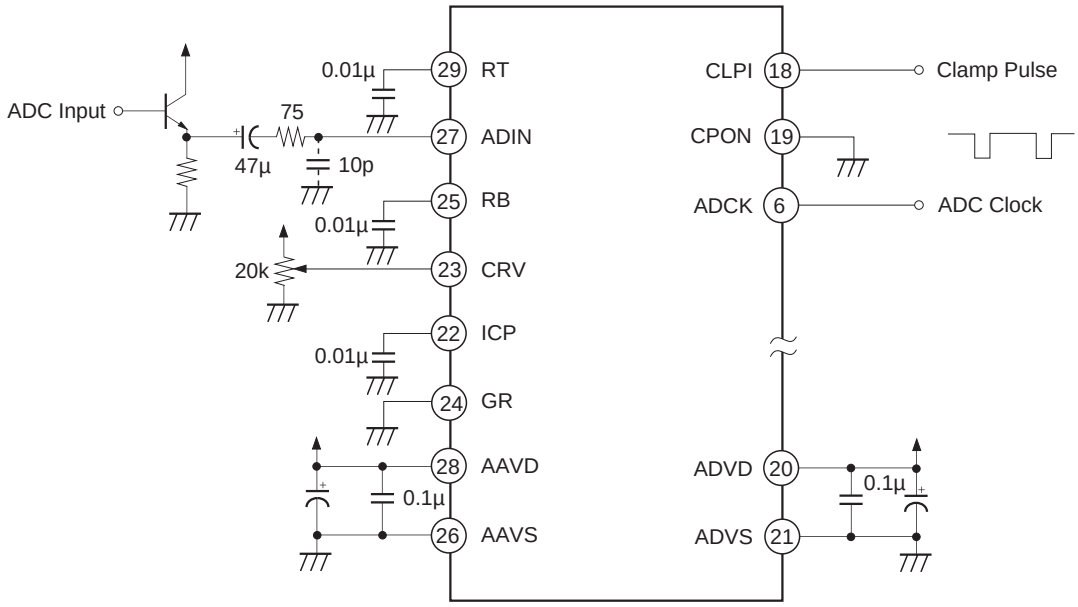
DAC Characteristics (V_{DD} = 5V, V_{RF} = 2V, I_{RF} = 3.3kΩ, R = 200Ω, Ta = 25°C, f = 10MHz)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Resolution	n	—	—	8	—	bit
Max. conversion speed	fmax	—	14.3	—	—	MSPS
Differential linearity error	E_D	—	–0.5	—	+0.5	LSB
Integral linearity error	E_L	—	–1.5	—	+1.5	LSB
Output full-scale voltage	V_{FS}	—	1.805	1.90	1.995	V
Output full-scale current	I_{FS}	—	—	9.5	15	mA
Output offset voltage	V_{OS}	—	—	—	1.0	mV
Precision guaranteed output voltage range	V_{OC}	—	1.8	—	2.1	V
Glitch energy	G_E	*1	—	30	—	pV-s

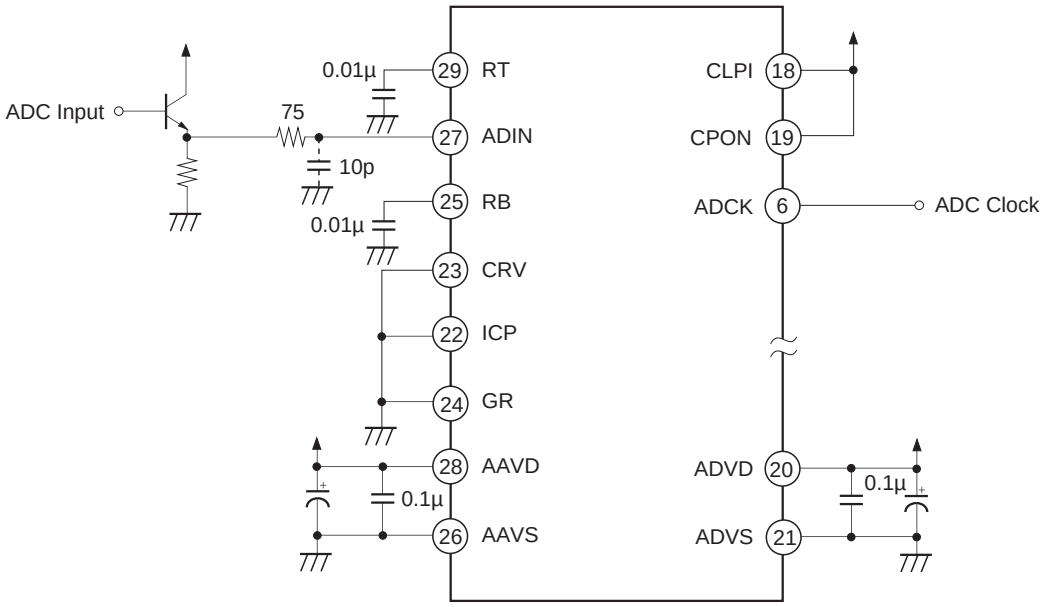
*1 R = 75Ω, 1Vp-p output

Application Circuit for A/D Converter

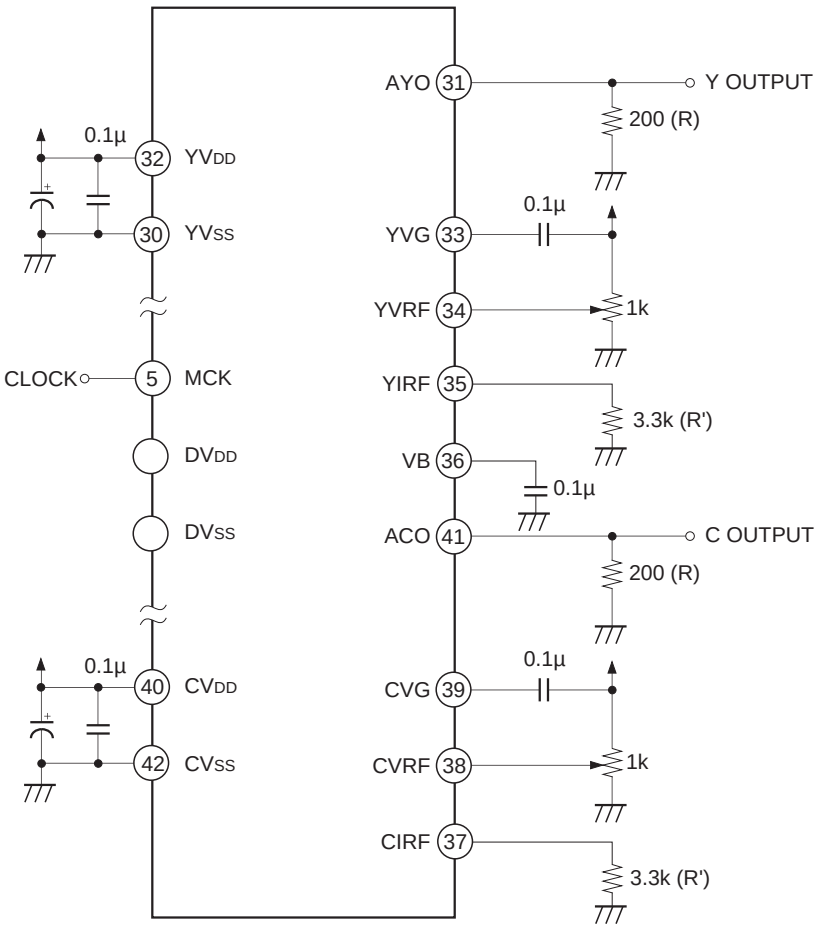
(1) In the case of input clamp pulse directly.



(2) In the case of not using the internal clamp circuit



Application Circuit for D/A Converter



• Method of Selecting Output Resistance

The CXD2043Q has a built-in current output-type D/A converter. To obtain the output voltages, connect resistances to AYO and ACO pins.

The voltage and current specifications are:

Output full-scale voltage: V_{FS} = 0.5 to 2.0V

Output full-scale current: I_{FS} = 0 to 15mA

Calculate the output resistance using the relationship $V_{FS} = I_{FS} \times R$. In addition, connect a resistance of 16 times the output resistance to the reference current pin (YIRF, CIRF). In the case where the value comes to be impractical, use a value of resistance as close to the value calculated as possible.

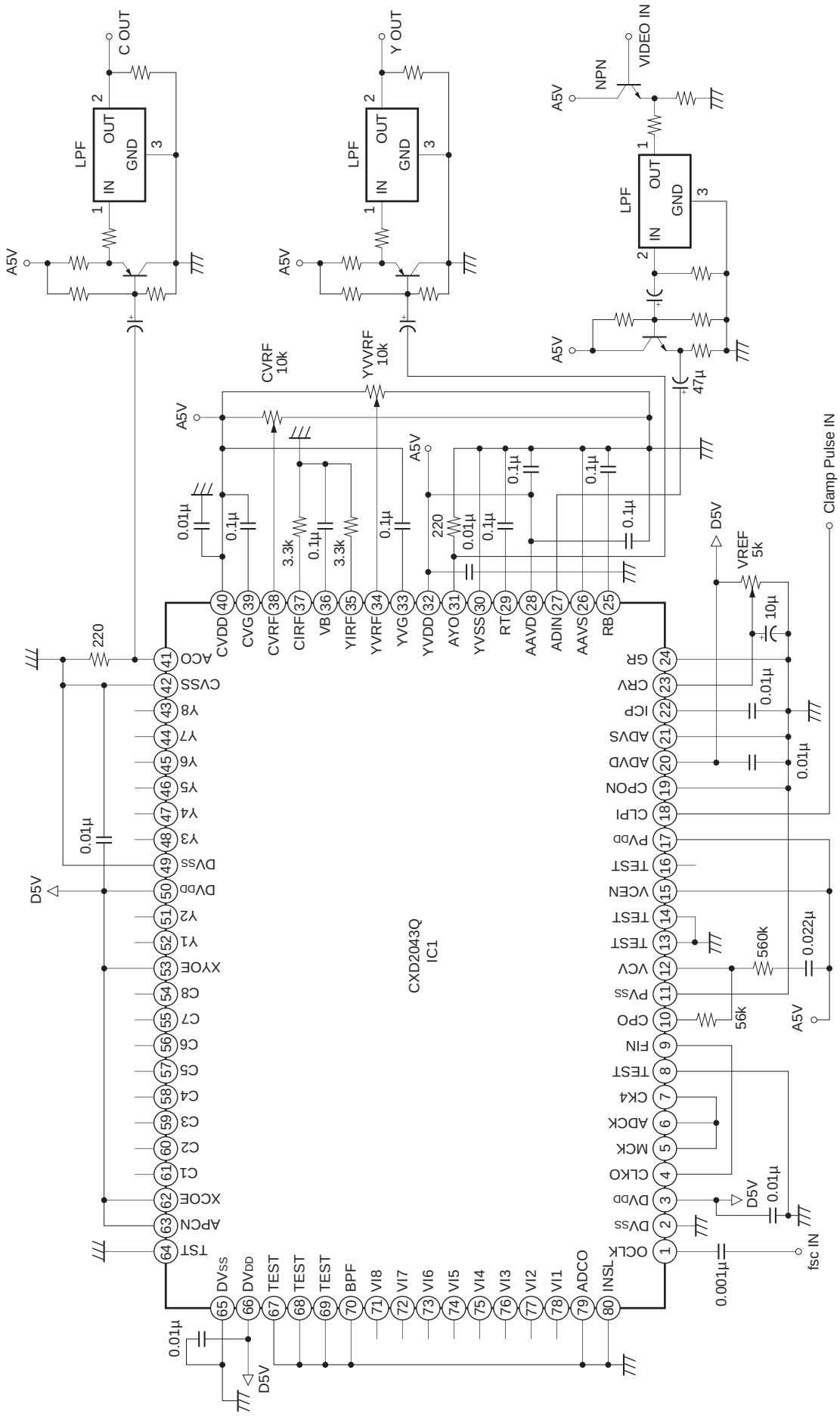
Note that, at this time, $V_{FS} = V_{RF} \times 16R/R'$ (V_{RF}: Pin voltage of YVRF and CVRF).

R is the resistance connected to AYO/ACO, and R' is the resistance connected to YIRF/CIRF. Power consumption can be reduced by using higher resistance values, but then glitch energy and data settling time increase contrastingly. Select optimum resistance values according to the system applications.

• V_{DD}, V_{SS}

Separate the analog and digital systems around the device to reduce noise effect. YV_{DD} and CV_{DD} are respectively by-passed to YV_{SS} and CV_{SS} as close to each other as possible through ceramic capacitor of approximately 0.1µF.

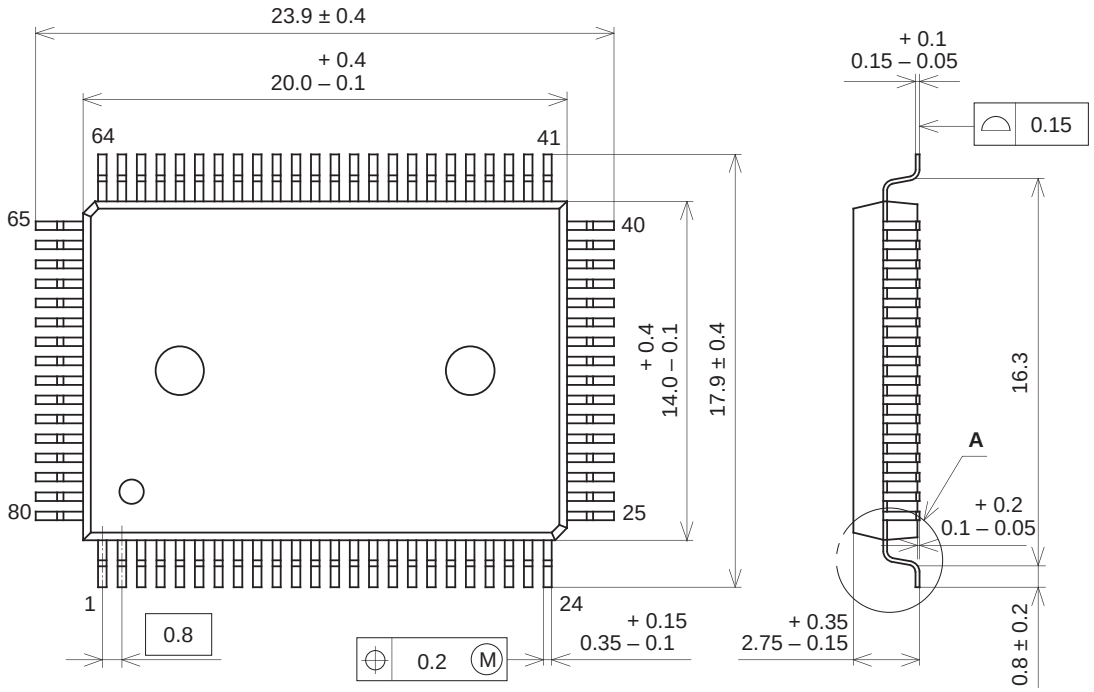
Application Circuit

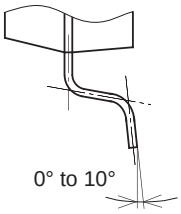


Application circuits shown are typical examples illustrating the operation of the devices. Sony cannot assume responsibility for any problems arising out of the use of these circuits or for any infringement of third party patent and other right due to same.

Package Outline Unit: mm

80PIN QFP (PLASTIC)





DETAIL **A**

SONY CODE	QFP-80P-L01
EIAJ CODE	QFP080-P-1420
JEDEC CODE	————

PACKAGE STRUCTURE

PACKAGE MATERIAL	EPOXY RESIN
LEAD TREATMENT	SOLDER PLATING
LEAD MATERIAL	42/COPPER ALLOY
PACKAGE MASS	1.6g